

Docket No.: 21737-00013-US  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Katsuki Hazama

Application No.: 09/438,295

Art Unit: 2135

Filed: November 12, 1999

Examiner: L. Hua

For: MULTILEVEL SEMICONDUCTOR MEMORY  
WRITE/ READ METHOD  
THERETO/THEREFROM AND STORAGE  
MEDIUM STORING WRITE/READ PROGRAM

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**AUG 18 2004**

**OFFICIAL**

**AMENDMENT AFTER FINAL ACTION (37 C.F.R. SECTION 1.116)**

MS AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

In response to the Office Action dated May 18, 2004 (Paper No. 9), favorable reconsideration of the application is requested.

Please amend the above-identified U.S. patent application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 18 of this paper.